Conductance of a Finite Quantum Wire Connected to Reservoirs

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Abstract

We study a nite quantum wire connected to external leads, and show that the conductance of the system signi cantly depends upon the length of the quantum wire and the position of the impurity in it. For a very long quantum wire and the impurity far away from its two ends, the conductance has the same behavior as that for an in nity quantum wire above some very little energy scale. However, for a very short quantum wire, the conductance is independent of the electron-electron interactions in it and closing to $e^2 = (2 \text{ h})$ in a higher temperature range. While, in a lower temperature range, the conductance shows the same property as that for an in nity quantum wire.

78.70 Dm, 79.60 Jv, 72.10 Fk

Recently, considerable e orts have been directed towards the study of the transport property of one-dimensional(ID) Tomonaga-Luttinger(TL) liquids [1{20]. For an in nity in purity-free quantum wire, the conductance is believed to be $ge^2 = (2 \text{ h})$ per spin orientation, where q is a dimensionless coupling strength parameter of the conduction electrons. For non-interacting electrons, q = 1. For repulsive interaction of the conduction electrons, g < 1, and the conductance is reduced. However, for a nite impurity-free quantum wire connected leads (reservoirs) which are characterized by Ferm i liquid, the conductance is believed to be $e^2 = (2 \text{ h})$ which is independent of the interactions in the quantum wire [16{20}], this surprising result derives from the boundary conditions between the TL liquid in the wire and the Fermi liquid in the leads at the ends of the wire. A recent experiment on a longer GaAs high-mobility quantum wires [10] shows that for a higher temperature, the conductance is very close to $e^2 = (2 h)$, but for a lower tem perature, the conductance has a power-law temperature dependence behavior, which is believed to be induced by the impurity scattering in the quantum wires. Therefore, this experiment really reveals the physical property of a nite quantum wire with impurity scattering. While, it is well-known that the backward scattering of the conduction electrons induced by the impurity is relevant in term inology of renorm alization group, the perturbation m ethods m ay fail for treating this kind of system, som e results obtained by perturbation methods are not reliable. In Ref. [15], by using bosonization method and unitary transformation, we can exactly treat the backward scattering of the conduction electrons and clearly show that the backward scattering significantly changes the correlation exponents of the conduction electrons. It is very discult to obtain these correlation exponents by the perturbation methods. In present Letter, encouraged by the exact solution of single quantum in purity scattering in TL-liquid, we study the conductance of a nite quantum wire connected to reservoirs. In contrast with an in nite quantum wire, it shows some dierent behaviors. The conductance drastically depends upon the length of the quantum wire and the position of the impurity. For a very long quantum wire, generally, it shows the same behavior as that for an in nity quantum wire above some very little energy scale. For a very short quantum wire, the conductance is independent of

the electron-electron interactions in the quantum wire in a higher temperature range, while its temperature dependence has the same form as that for the in nity quantum wire in a lower temperature range.

The Hamiltonian describing the 1D TL-liquid is generally given by

$$H_{0} = ih_{\Psi} \int_{a}^{Z_{L}} dx \left[f_{R}^{+}(x) \theta_{x} R(x) + f_{L}^{+}(x) \theta_{x} L(x) \right]$$
 (1)

$$H_{I} = \frac{V^{Z_{L} a}}{2} dx (_{R} (x) + _{L} (x))^{2}$$
 (2)

$$H_{im} = V_{2k_F} \begin{bmatrix} + \\ R \end{bmatrix} (0) + (0) + (1) + (0) + (0)$$
 (3)

where $_R$ (x)($_R^+$ (x)) is the eld operator of ferm ions that propagate to the right with wave vectors $_R^+$ + $_R^+$, $_L^-$ (x)($_L^+$ (x)) is the eld operator of left propagating ferm ions with wave vectors $_R^+$ + $_R^+$, $_L^-$ (x) ($_L^+$ (x)) is the eld operator of left propagating ferm ions with wave vectors $_R^+$ + $_R^+$, $_L^+$ (x) ($_L^+$ (x)) are the electron density operators; the spectrum of the electrons is linearized near the Ferm i points and $_R^+$ is the Ferm i velocity; V describes density-density interaction with momentum transferring much smaller than $_R^+$. $_L^+$ = $_L^+$ V (k = $_L^+$ 2k $_R^+$) is the backward scattering potential of an impurity residing at x = 0 on the conduction electrons, for simplicity, we have omitted the forward scattering potential because it has less in uence on the conductance. L is the length of the quantum wire, and 0 < a L=2. For simplicity, the reservoirs are assumed to be described by free electron systems.

In the previous bosonization treatment of the H am iltonians (1), (2) and (3), one directly substitutes the bosonic representation of the ferm ion elds $_{R(L)}$ (x) into Equ.(3) and obtains a non-linear term which make the system be more discult treated. To more electively study the physical property of the system described by the H am iltonians (1), (2) and (3), we choose other new ferm ionic eld operators

$$_{1}(x) = \frac{1}{\frac{2}{2}}(_{R}(x) + _{L}(_{X})); \quad _{2}(x) = \frac{1}{\frac{2}{2}}(_{R}(x) \quad _{L}(_{X}))$$
 (4)

It is easy to check that the operators $_{1(2)}$ (x) satisfy the standard anticom m utation relations. In terms of these new ferm ion elds $_{1(2)}$ (x), the cross term of the ferm ion elds $_{R(L)}$ (x) in (3) can be written in a very simple form which can be cancelled by a simple unitary transform ation. However, the Hamiltonian (2) becomes complex. Taking usual bosonization procedure [1,21,22] for $_{1(2)}$ (x), the Hamiltonians (1), (2) and (3) can be written as

$$H_{0} = \frac{hv_{F}}{4} \int_{0}^{Z_{L}} dx [(\theta_{x_{1}}(x))^{2} + (\theta_{x_{2}}(x))^{2}]$$
 (5)

$$H_{I} = \frac{V}{4} \int_{a}^{Z_{L}} dx f[_{1}(x) + _{2}(x)]^{2} + [_{1}(x) + _{2}(x)][_{1}(_{x}) + _{2}(_{x})][_{1}(_{x}) + _{2}(_{x})]$$

$$+ [_{1}^{+}(x) _{2}(x) + _{2}^{+}(x) _{1}(x)]^{2}$$

$$+ [_{1}^{+}(x) _{2}(x) + _{2}^{+}(x) _{1}(x)][_{1}^{+}(_{x}) _{2}(_{x}) + _{2}^{+}(_{x}) _{1}(_{x})]g$$
(6)

$$H_{im} = \frac{hv_F}{2} (\theta_{x-1}(x)) \quad Q_{x-2}(x))_{\dot{x}=0}$$
 (7)

where = $\arctan(V_{2k_F} = (hv_F))$ is a phase shift induced by the backward scattering potential V_{2k_F} . This replace of V_{2k_F} by can be judged by the usual Born-approximation method and the solution of the X-ray absorption in usual metals [23]. For simplicity, we write out the last two terms in (6) by the fermion elds $_{1(2)}(x)$. If we use the boson elds $_{1(2)}$ to write out these two terms, they become very complex cosine forms. However, no matter which description we use, the nal result is same. The bosonization representation of the fermion elds $_{1(2)}$ can be written as [1,21,22]

$$_{1(2)}(x) = (\frac{D}{2 \text{ hv}_{F}})^{1=2} \exp f \text{ i}_{1(2)}(x)g$$
 (8)

where D is the band width of the conduction electrons in the quantum wire, $_{1(2)}(x) = _{1(2)}^+(x)$ $_{1(2)}(x)$ are the density operators of the ferm ion elds $_{1(2)}(x)$, and have relations with the boson elds $_{1(2)}(x)$: $@_{x=1(2)}(x) = 2_{-1(2)}(x)$. In terms of the new boson and ferm ion elds $_{1(2)}(x)$ and $_{1(2)}(x)$, the Hamiltonian (6) becomes complex, but the Hamiltonian (7) becomes very simple. Generally, due to the simple form of the Hamiltonian (7) which is proportional to the density of the ferm ion elds $_{1(2)}(x)$ at the impurity site x = 0, using an unitary transform ation we can eliminate it, so that the problem is simplied as that we only need to treat a Hamiltonian similar to (5) and (6). However, the backward scattering

interaction drastically in uences the behavior of the conduction electrons through changing interactions among them. Therefore, we cannot simply eliminate the backward scattering term by an unitary transform ation and meanwhile leave the Hamiltonians (5) and (6) intact.

To cancel the -term in (7) and simplify the system, we adopt the following steps [15]:

1). Taking the unitary transform ation

$$U = \exp fi \frac{1}{2} (_{1}(0) _{2}(0))g$$
 (9)

we have the following relations

$$U^{+} (H_{0} + H_{im})U = H_{0}$$

$$U^{+} H_{I}U = \frac{V}{4} \int_{a}^{Z_{L}} dx f[_{1}(x) + _{2}(x)]^{2} + [_{1}(x) + _{2}(x)][_{1}(_{x}) + _{2}(_{x})][_{1}(_{x}) + _{2}(_{x})$$

2). Perform ing the gauge transform ations

$$_{1(2)}(x) = _{1(2)}(x)e^{i_{1(2)}}; _{1} _{2} =$$
 (10)

we have the relations

$$U^{+}H_{I}U = H_{I}^{(1)} + H_{I}^{(2)}$$

$$H_{I}^{(1)} = \frac{V}{4} \int_{a}^{Z_{L}} \int_{a}^{a} dx f[_{1}(x) + _{2}(x)]^{2} + [_{1}(x) + _{2}(x)][_{1}(-x) + _{2}(-x)]$$

$$+ [_{1}^{+}(x) _{2}(x) + _{2}^{+}(x) _{1}(x)]^{2}$$

$$\infty s(2) [_{1}^{+}(x) _{2}(x) + _{2}^{+}(x) _{1}(x)][_{1}^{+}(-x) _{2}(-x) + _{2}^{+}(-x) _{1}(-x)]g$$

$$H_{I}^{(2)} = \frac{V}{4} \int_{0}^{Z_{L}} \int_{a}^{a} dx f \frac{\cos(4)}{2} \int_{1}^{1} f(-x) _{2}(x) + f(-x) _{2}^{+}(x) _{1}(x)]^{2}$$

$$+ [_{1}^{+}(x) _{2}(x) - _{2}^{+}(x) _{1}(x)]^{2}g$$

$$+ i sin(2) \int_{a}^{Z_{L}} \int_{a}^{a} dx [_{1}^{+}(x) _{2}(x) - _{2}^{+}(x) _{1}(x)]$$

$$f(-x) _{2}(-x) + f(-x) _{1}^{+}(-x) _{1}(-x)]$$

3). Re-de ning the left-and right-moving electron ferm ions

$${R}(x) = \frac{1}{2} [1(x) + 2(x)]; \quad L(x) = \frac{1}{2} [1(x) + 2(x)]$$

$${R}(L)(x) = (\frac{D}{2 \text{ hv}_{E}})^{1-2} \exp f \quad i_{R(L)}(x)g; \quad \theta_{X R(L)}(x) = 2_{R(L)}(x) \quad (11)$$

where $_{R (L)}(x) = _{R (L)}^{+}(x) _{R (L)}(x)$ are the density operators of the electron elds $_{R (L)}(x)$, the H am iltonians H $_{I}^{(1)}$ and H $_{I}^{(2)}$ can be rewritten as

$$H_{I}^{(1)} = \frac{V}{2} \int_{a}^{Z_{L}} dx f[_{R}(x) + _{L}(x)]^{2} + \frac{1 \cos(2)}{2} [_{R}(x) + _{L}(x)][_{R}(x) + _{L}(x) + _{L}(x)][_{R}(x) + _{L}(x)][_{R}(x) + _{L}(x) + _{L}(x) + _{L}(x)][_{R}(x) + _{L}(x) + _{L}(x) + _{L}(x)][_{R}(x) + _{L}$$

$$H_{I}^{(2)} = i \frac{V \sin(2)}{4} \int_{a}^{Z_{L}} dx [_{R}(x) _{L}(x)][_{L}^{+}(x) _{R}(x) _{R}(x) _{R}(x)] + \frac{V}{8} (1 \cos(4)) \int_{0}^{Z_{L}} dx [_{R}(x) _{L}(x) _{R}(x) _{R}(x) _{R}(x)]$$

It is worth notice that the H am iltonian $H_{I}^{(2)}$ only contributes high order corrections because the rst term has the conformal dimension 2 and the last term has the conformal dimension = 2, and at the weak (0) and strong (=2) coupling $\lim_{n \to \infty} \mathbb{E}[x]$ they all tend to zero. Therefore, for $\lim_{n \to \infty} \mathbb{E}[x]$ we can neglect it.

4). De ning a set of new boson elds

$$f(x) = \left(\frac{G(x)}{\cosh(x_1 + x_2)}\right)^{1-2} \left[\cosh(x_1) + f(x_2) + \sinh(x_1) + f(x_2)\right]$$

$$f(x) = \left(\frac{1}{G(x_1) \cosh(x_1 + x_2)}\right)^{1-2} \left[\cosh(x_2) + f(x_2) + f(x_2) + f(x_2)\right] \qquad (12)$$

where G () = [(1) (1
$$\cos(2)^{\frac{1}{2}}] = [(1+)(1+\cos(2))^{\frac{1}{2}}]$$
, $\tan(2_1) = (1+\cos(2))$, $\tan(2_2) = (1+\cos(2)) = 2$, $\tan(2_2) = 2$,

The total Hamiltonian of the system can be simplied as a very simple form

$$H = \frac{hv_F}{4 \text{ a}}^{Z_{L} \text{ a}} dx [(\theta_x + (x))^2 + (\theta_x - (x))^2]$$
 (13)

where $v_F = v_F \cosh(\frac{1}{2})(\frac{1-(\cos(2))^2}{1-2})^{1-4}$, $g = (\frac{1}{1+})^{1-2}$ is a dimensionless coupling strength parameter, where $= V = (2 \ hv_F + V)$. Here we have omitted some higher order terms [15] which only give less important high order correction to the conductance. However, the dual boson elds (x) satisfy the following commutation relations

$$[0_x + (x); (y)] = i2 (x y) + i2 (x + y) tan (2)$$

 $[0_x (x); + (y)] = i2 (x y) + i2 (x + y) tan (2)$
(14)

which have an anomaly term i2 $(x + y) \tan (x + y) \cdot x = 0$. This term is zero at the weak 0 and strong = 2 coupling lim its. A coording to these commutation relations of the dual boson elds (x), for example, we can de ne the conjugate momentum eld P (x) of the boson eld (x) as

$$\frac{1}{2} \mathcal{Q}_{x} + (x) = P + (x) + \tan(x_1 + x_2) P + (x); \quad P(x); \quad (y) = i + (x_1 + y_2)$$
 (15)

and then we can exactly solve the Hamiltonian (13). Therefore, we can calculate the conductance for any backward scattering potential.

For sim plicity, we rst consider a special case: = 0, which corresponds to the weak backward scattering limits. In this case, the propagators of the boson eld (x) satisfy the following equation

$$f \quad \underset{q}{\mathbb{Q}} \left(\overset{V}{-} \underset{q}{\mathbb{Q}}_{x} \right) + \frac{\dot{\mathcal{L}}^{2}}{Vq} g G_{\dot{\mathcal{L}}} \left(x; x^{0} \right) = (x \quad \overset{0}{x})$$
 (16)

where $G_{\downarrow}(x;x^0) = \frac{1}{2} {R_{1=(k_B T)} \over 0} d < T$ (x;) $(x^0;0) > e^{i x}$, where T is temperature, $v = v_F = g$. Using the boundary conditions [16] of the propagator $G_{\downarrow}(x;x^0)$, we can easily obtain the following equation at the impurity site x = 0

$$G_{\downarrow}(0;0)'\frac{K}{2j!}j$$
 (17)

where the dimensionless coupling strength parameter K satis es the following relations

$$K = \begin{cases} g; & \text{j!-j} & \text{v=a} \\ \frac{2g}{g+1}; & \text{v=L} & \text{j!-j} & \text{v=a} \\ \vdots & \text{j!-j} & \text{v=L} \end{cases}$$
(18)

However, for a general phase shift , we can obtain the following expression of the propagator $G_{\pm}(x;x^0)$ at the impurity site x=0

$$G_{\downarrow}(0;0)' \frac{G()K}{2 j! j}$$
 (19)

where the dimensionless coupling strength parameter K satis es the following relations

$$K = \begin{cases} 2 \\ + G() \end{cases}; \quad v^{\circ} = A$$

$$\frac{2}{G()}; \quad v^{\circ} = L \quad v^{\circ} = A$$

$$\frac{2}{G()}; \quad y^{\circ} = L$$

$$(20)$$

where = $[1 + \tan(_1 _2)]=[1 + \tan^2(_1 _2)], v^0 = v_F = g.$

Now we calculate the conductance of the system. To this end, we set do not a charge density operator Q(x), and then use the continuous equation to obtain the current density operator J(x). The charge density operator Q(x) is equal to e(R(x) + L(x)). Under the unitary and gauge transformations (9) and (10), it can be written as

$$U^{+}_{R}(x)U = \begin{cases} & & \\ & &$$

$$U^{+}_{L}(x)U = \begin{cases} & & & \\ &$$

It is worth noting that if the phase shift—takes the values =2, the electrons are completely re-ected at the impurity site x=0, and we have the relations: $U^+_R(x)U^-_R(x$

$$J(x) = \frac{e}{2} \left(\frac{\cosh(x_{1} - x_{2})}{2} \right)^{1-2} f \qquad \frac{g_{1}(x_{2})}{g_{2}(x_{2})}^{1-2} [0_{1} + (x_{2}) - (x_{2})]^{1-2} [0_{2} + (x_{2})$$

where $g_1() = (1 ^1)^{-2} = (1 \cos(2))^{1/2}$, $g_2() = (1 + \cos(2))^{1/2} = (1 +)^{1-2}$. Using K ubo form ula of the conductance, and the expression of the propagators $G_{+}(x 0; x^{0} 0)$ in (19) and (20), we can obtain the following electric conductance

$$\downarrow (x \quad x^{0} \quad 0) = \begin{cases}
\frac{e^{2}}{2 h} & \frac{^{2}G() \cosh(_{1} \quad _{2})}{g_{2}()} + A \cdot^{2}; \quad j + j \quad v^{0} = a \\
\frac{e^{2}}{2 h} & \frac{^{2} \cosh(_{1} \quad _{2})}{g_{2}()} + B \cdot^{2}; \quad j + j \quad v^{0} = L
\end{cases}$$
(24)

= G () \cosh ($_1$ $_2$)=(g_2 ()), = \cosh ($_1$ $_2$)= g_2 (), A and B are constants. This is our central result of present paper. The temperature dependence of the electric conductance + (x \mathbf{x}^{0} 0) can be obtained through replacing the frequency ! by the tem perature T. It is necessary to mention that as the frequency ! and the temperature T tend to zero, f!; Tg! 0, the phase shift takes the values =2, and the electric conductance is equal to zero. This behavior can be easily understood by using the renormalization group [5] that because the backward scattering term is relevant, the renormalized backward scattering potential V_{2k_F} goes to in nity in the low energy \lim it, therefore, the phase shift by the backward scattering potential takes the values =2. The electric conductance (24) does not contradict previous work. As f!; Tq = 0, the electrons are completely rejected on the impurity site x = 0 for the repulsive electron-electron interaction. It is worth notice that the electric conductance signi cantly depends upon the length of the wire, and the position of the impurity. In generally, for a very long wire, L! 1, the electric conductance is in the range of $j \nmid j$ v = a. For an impurity-free system, = 0, the electric conductance is equal to $ge^2 = (2 \text{ h})$. If there exists impurity scattering, the electric conductance is $^2e^2 = (2 \text{ gh})$ in the low energy lim it. All these properties are the same as that for an in nite quantum wire. However, for a short quantum wire, in the low energy limit, the electric conductance

falls in the range of jtj $v^0=L$, for the impurity-free case, the electric conductance is equal to $e^2=(2\ h)$ which is independent of the electron-electron interactions in the quantum wire [16{20}]. As including the impurity scattering, for the weak backward scattering, the electric conductance is still very closing to $e^2=(2\ h)$. For the strong backward scattering, the electric conductance is the same as that for the in nite quantum wire. However, to consider the temperature dependence of the conductance, we must calculate the tunneling conductance at the impurity site x=0 which derives from the quantum uctuation of collective excitation modes of the system, because Eq.(24) only gives a higher order temperature dependence.

To calculate the tunneling conductance of the system , we can do not the following tunneling current operator at the im purity site x=0 as

$$I_{tunn} = \frac{et_0}{2} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \end{pmatrix} \begin{pmatrix} & + \\ 2 & \end{pmatrix} \end{pmatrix} \begin{pmatrix} & + \\ 2 &$$

where t_0 is the tunneling probability am plitude. This de nition and the following calculation of the tunneling conductance are meaningful only at the strong coupling region determined by the phase shift . In terms of the boson elds (x), it can be written as

$$I_{tunn} = \frac{et_0 D}{2 hv_F} \cos[(\frac{2G () \cosh(_1 _2)}{g_2 ()})^{1-2} (0)]$$
 (25)

Therefore, by using K ubo form ula of the conductance, we can obtain the following tunneling conductance

far away from the ends of the quantum wire, the conductance of the system shows the same behavior as that for an in nite quantum wire. While, for the case of a short quantum wire, the usual experimental energy is in the range of $j \not = L$, the conductance is independent of the electron-electron interactions in the quantum wire in a higher temperature range (but still leaving the condition $j \not = L$ intact), and its temperature dependence is the same as that for an in nite quantum wire in the lower temperature range.

In sum mary, using the bosonization method and the unitary transformation, we have studied the system of a nite quantum wire connected to leads, and shown that in contrast with an in nity quantum wire, it signicantly relies upon the length of the wire and the position of the impurity in the wire. For a very short quantum wire, in the higher temperature range, the conductance is independent of the electron-electron interactions in the wire and is very closing to $e^2 = (2 \text{ h})$. However, in the lower temperature range, it is the same as that for an in nity quantum wire.

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